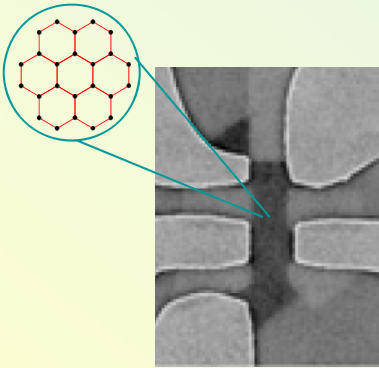


Electronic properties of graphene, from 'high' to 'low' energies.

Vladimir Falko, Lancaster University



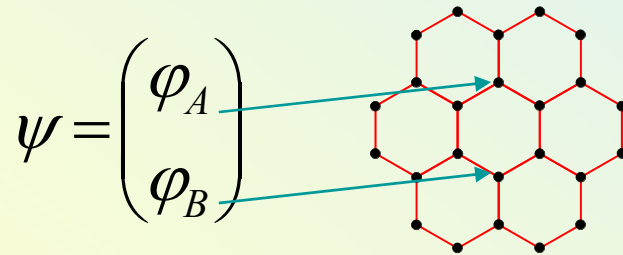
Graphene for beginners: tight-binding model.
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$$H_{AB,K} = \gamma_0 \left[e^{-i\frac{2\pi}{3}} e^{-i(\frac{a}{2}p_x + \frac{a}{2\sqrt{3}}p_y)} + e^{i\frac{a}{\sqrt{3}}p_y} + e^{i\frac{2\pi}{3}} e^{i(\frac{a}{2}p_x - \frac{a}{2\sqrt{3}}p_y)} \right] \\ \approx \frac{\sqrt{3}}{2} \gamma_0 a (p_x - ip_y) = v\pi^+$$

$$H_{BA,K} \approx \frac{\sqrt{3}}{2} \gamma_0 a (p_x + ip_y) = v\pi$$

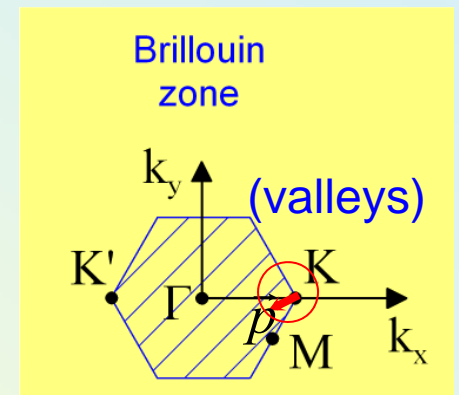
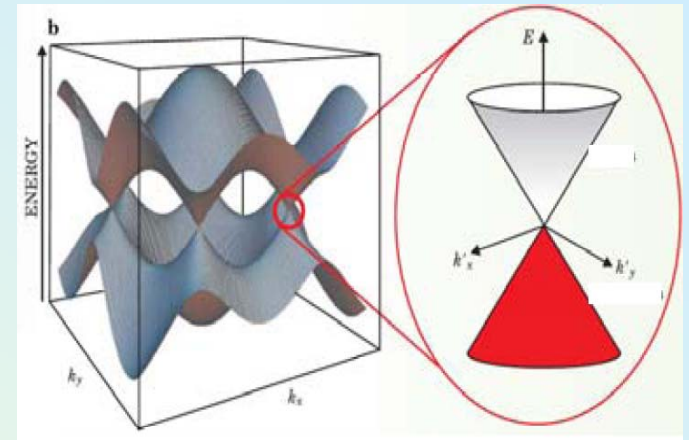
**Bloch function amplitudes on the AB sites ('isospin')
mimic spin components of a relativistic particle in
a Dirac-type Hamiltonian**



$$\hat{H} = v \begin{pmatrix} 0 & \pi^+ \\ \pi & 0 \end{pmatrix} = v \vec{\sigma} \cdot \vec{p}$$

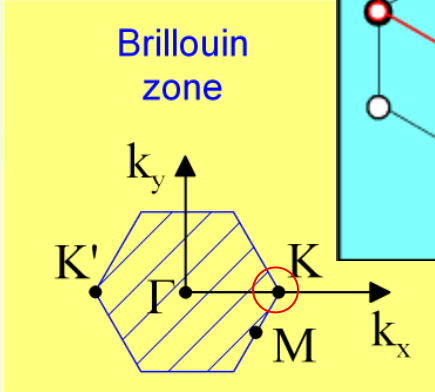
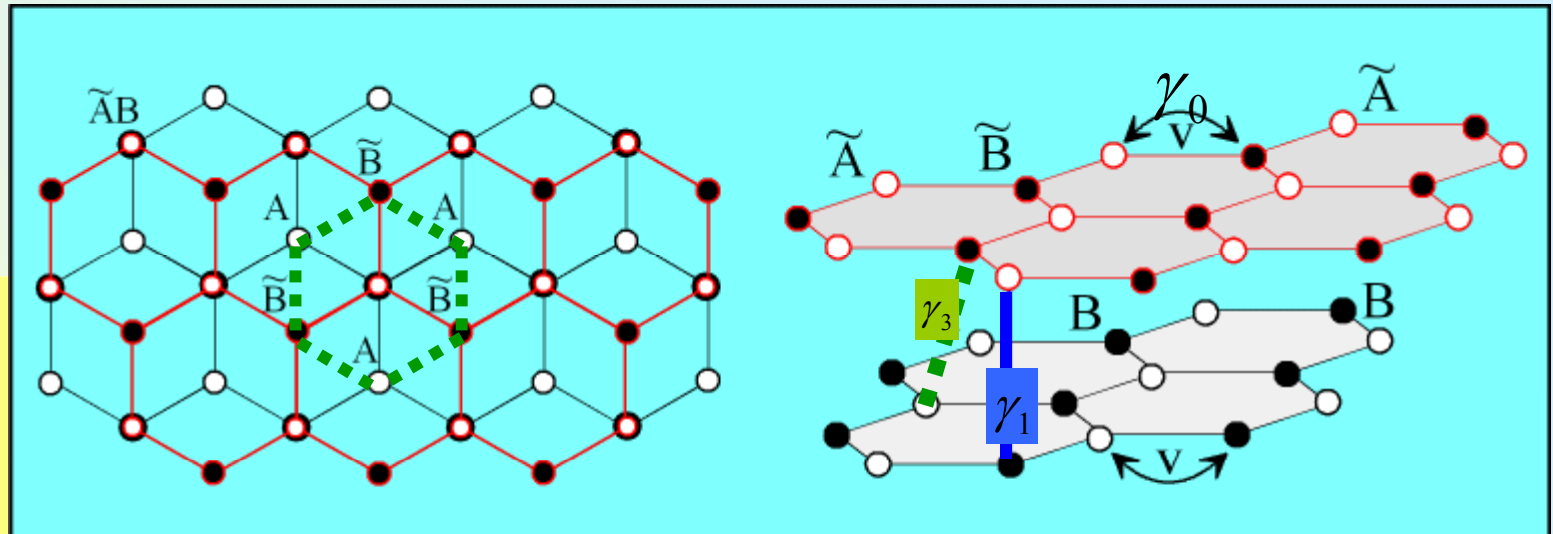
McClure – Phys. Rev. 104, 666 (1956)

$$\pi = p_x + ip_y$$



$$v \sim 10^8 \frac{cm}{sec}$$

Electrons in bilayer graphene

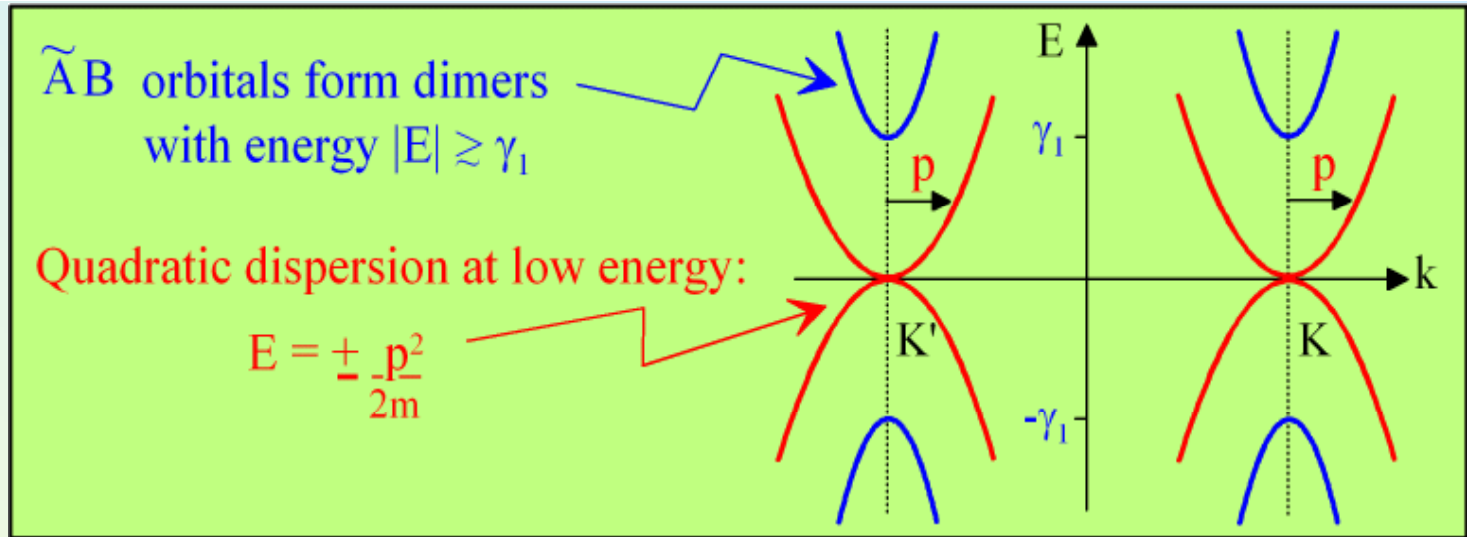


Slonczewski-Weiss-McClure parameterization for Bernal stacking

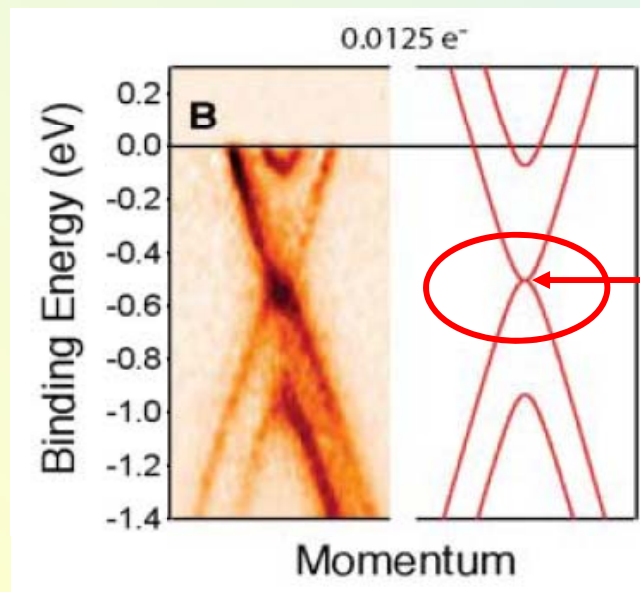
$$\begin{pmatrix}
 0 & 0 & 0 & v\pi^+ \\
 0 & 0 & v\pi & 0 \\
 0 & v\pi^+ & 0 & \gamma_1 \\
 v\pi & 0 & \gamma_1 & 0
 \end{pmatrix}
 \begin{pmatrix}
 A \\
 \tilde{B} \\
 \tilde{A} \\
 B
 \end{pmatrix}$$

$$\pi = p_x + ip_y$$

McCann & VF
 PRL 96, 086805
 (2006)



$$\gamma_1 \approx 0.4 eV$$



ARPES: heavily doped bilayer graphene

synthesized on silicon carbide

T. Ohta *et al* – Science 313, 951 (2006)

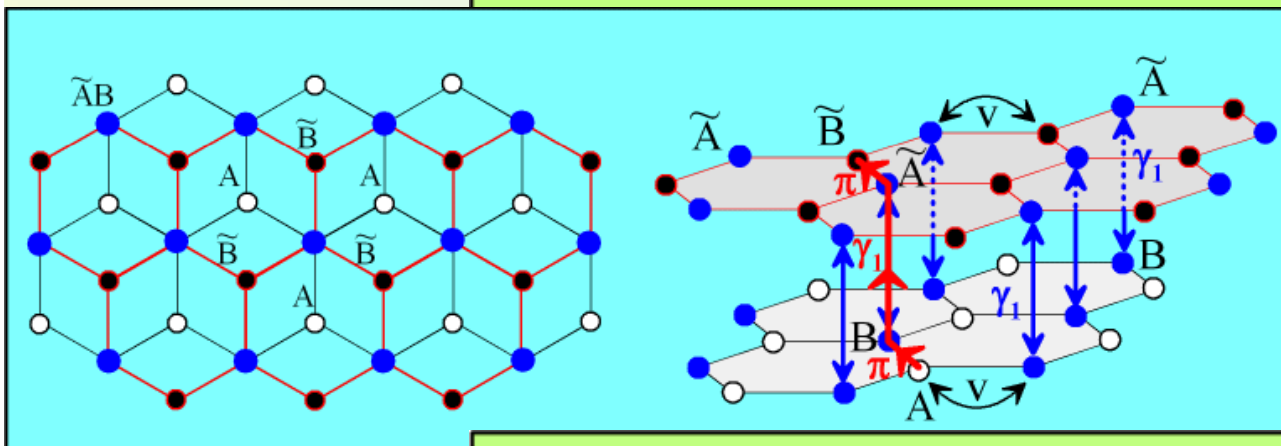
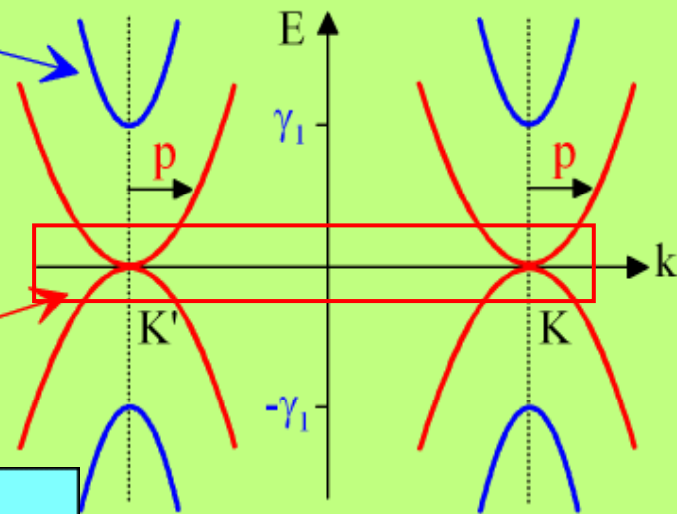
(Rotenberg's group at Berkeley NL)

Fermi level in undoped bilayer graphene

$\tilde{A}\tilde{B}$ orbitals form dimers
with energy $|E| \geq \gamma_1$

Quadratic dispersion at low energy:

$$E = \pm \frac{p^2}{2m}$$



$$\gamma_1 \approx 0.4eV$$

$$m \approx 0.035m_e$$

Bilayer Hamiltonian written in a 2 component basis of A and \tilde{B} sites

$$H = \frac{-1}{2m} \begin{pmatrix} 0 & (\pi^+)^2 \\ \pi^2 & 0 \end{pmatrix}$$

Berry phase 2π electrons

A to \tilde{B} hopping

- bottom layer $A \rightarrow B$ (factor π)
- switch layers via dimer $B\tilde{A}$ (γ_1^{-1})
- top layer $\tilde{A} \rightarrow \tilde{B}$ (factor π)

$$\pi = p_x + ip_y = p e^{i\theta}$$

mass
 $m = \gamma_1 / v^2$

McCann & VF
PRL 96, 086805
(2006)

Monolayer
(Dirac point)

$$H = v \begin{pmatrix} 0 & \pi^+ \\ \pi & 0 \end{pmatrix}$$

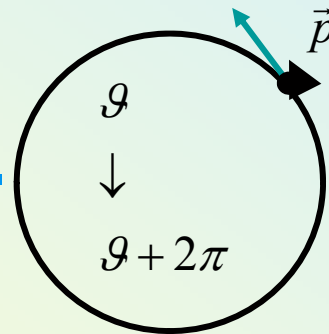
$$\pi = p e^{i\vartheta}$$

bilayer:

$$H = \frac{-1}{2m} \begin{pmatrix} 0 & (\pi^+)^2 \\ \pi^2 & 0 \end{pmatrix}$$

$$\psi_{\vec{p}} = \frac{1}{\sqrt{2}} \begin{pmatrix} 1 \\ \pm e^{-i\vartheta} \end{pmatrix}$$

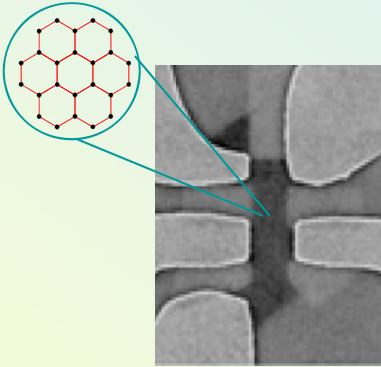
$$\psi \rightarrow e^{2\pi \frac{i}{2} \sigma_3} \psi = e^{i\pi \sigma_3} \psi$$



Berry phase

$$\psi \rightarrow e^{4\pi \frac{i}{2} \sigma_3} \psi = e^{i2\pi \sigma_3} \psi$$

$$\psi_{\vec{p}} = \frac{1}{\sqrt{2}} \begin{pmatrix} 1 \\ \pm e^{-i2\vartheta} \end{pmatrix}$$



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2D Landau levels

semiconductor
 QW / heterostructure
 (GaAs/AlGaAs)

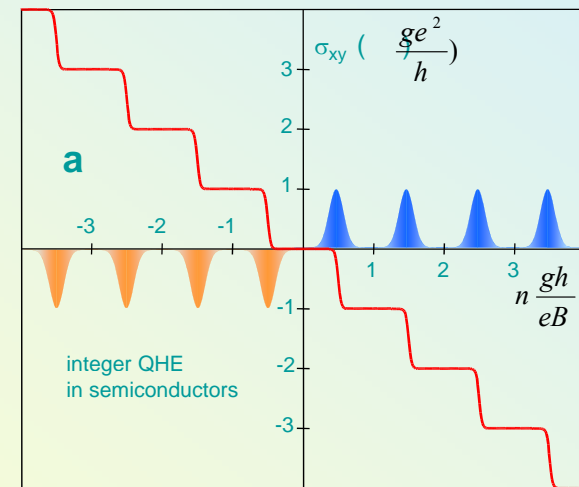
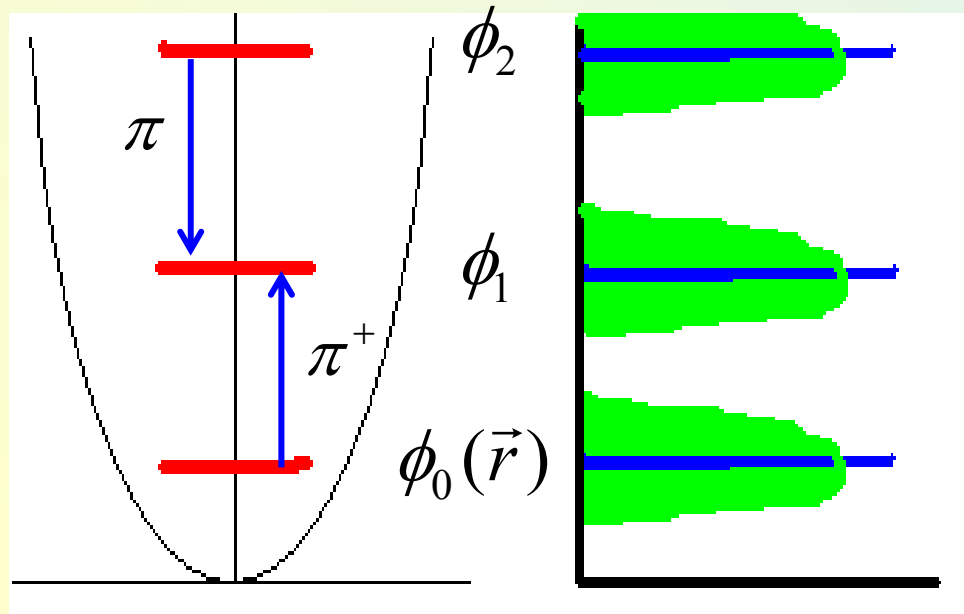
$$\vec{p} = -i\hbar\nabla - \frac{e}{c}\vec{A}, \quad \text{rot}\vec{A} = B\vec{l}_z$$

$$\pi = p_x + ip_y; \quad \pi^+ = p_x - ip_y$$

$$\pi\phi_0 = 0$$

$$\phi_{n+1} = \frac{\lambda_B}{\sqrt{n+1}} \pi^+ \phi_n$$

$$H = \frac{\vec{p}^2}{2m} = \frac{\pi\pi^+ + \pi^+\pi}{4m} \Rightarrow (n + \frac{1}{2})\hbar\omega_c \leftarrow \text{energies / wave functions}$$



Landau levels and the QHE

Monolayer:

$$H = v\xi \begin{pmatrix} 0 & \pi^+ \\ \pi & 0 \end{pmatrix}$$

Bilayer:

$$H = \frac{-1}{2m} \begin{pmatrix} 0 & (\pi^+)^2 \\ \pi^2 & 0 \end{pmatrix}$$

In a perpendicular magnetic field B:

$$\vec{p} = -i\hbar\nabla - \frac{e}{c}\vec{A}, \quad \text{rot}\vec{A} = B\vec{l}_z$$

$$\pi = p_x + ip_y; \quad \pi^+ = p_x - ip_y$$

$\pi \rightarrow$ lowering operator
 $\pi^+ \rightarrow$ raising operator
 }
 of magnetic oscillator
 eigenstates ϕ_n

We are able to determine the spectrum of discrete Landau levels

States at zero energy are determined by

$$\text{monolayer: } \pi\phi_0 = 0$$

$$\text{bilayer: } \pi^2\phi_0 = \pi^2\phi_1 = 0$$

$$H_1 \psi = v \begin{pmatrix} 0 & \pi^+ \\ \pi & 0 \end{pmatrix} \begin{pmatrix} \phi_0 \\ 0 \end{pmatrix} = 0$$

$$H_2 \psi = \frac{-1}{2m} \begin{pmatrix} 0 & \pi^{+2} \\ \pi^2 & 0 \end{pmatrix} \begin{pmatrix} \phi_{0,1} \\ 0 \end{pmatrix} = 0$$

$$\begin{pmatrix} \phi_0 \\ 0 \end{pmatrix}$$

$$\begin{pmatrix} \phi_0 \\ 0 \end{pmatrix}, \begin{pmatrix} \phi_1 \\ 0 \end{pmatrix}$$

$$\mathcal{E} = 0$$

**4J-degenerate
zero-energy Landau level**
J=1 - monolayer
J=2 - bilayer
 also, two-fold real
 spin degeneracy

$$\begin{pmatrix} 0 & (-\pi^+)^J \\ (-\pi)^J & 0 \\ & & 0 & (\pi^+)^J \\ \pi^J & & 0 & 0 \end{pmatrix} \begin{pmatrix} A + \\ \tilde{B} + \\ \tilde{B} - \\ A - \end{pmatrix}$$

valley index
↓

All non-zero eigenvalues can be easily found by diagonalizing H^2

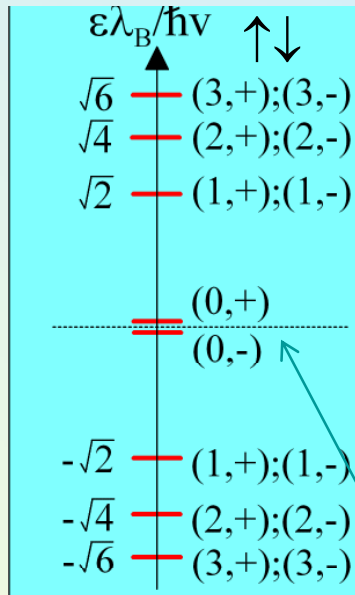
$$H = v \begin{pmatrix} 0 & \pi^+ \\ \pi & 0 \end{pmatrix}$$

energy scale $\hbar v / \lambda_B$

where $\lambda_B = \sqrt{\frac{\hbar}{eB}}$

state at zero energy

$$\pi \phi_0 = 0$$



Monolayer

McClure - Phys. Rev. 104, 666 (1956)
 Haldane, PRL 61, 2015 (1988)
 Zheng & Ando - PRB 65, 245420 (2002)

$$\varepsilon^\pm = \pm \sqrt{2n} \frac{v}{\lambda_B}$$

with 4-fold degenerate $\varepsilon=0$ Landau level

$$\begin{pmatrix} \phi_0 \\ 0 \end{pmatrix}, \begin{pmatrix} \phi_1 \\ 0 \end{pmatrix}$$

$$H = \frac{-1}{2m} \begin{pmatrix} 0 & (\pi^+)^2 \\ \pi^2 & 0 \end{pmatrix}$$

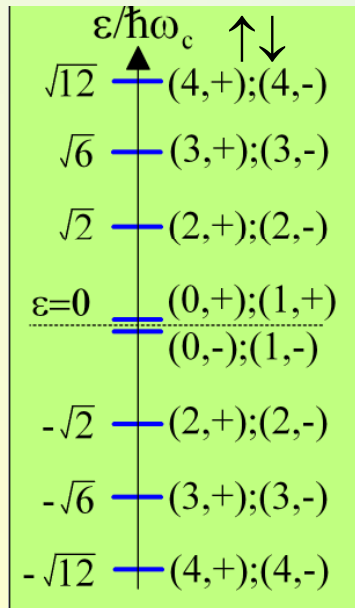
energy scale $\hbar \omega_c$

where $\omega_c = \frac{eB}{m}$
 $m \approx 0.035m_e$

states at zero energy:

$$\pi^2 \phi_0 = 0$$

$$\pi^2 \phi_1 = 0$$

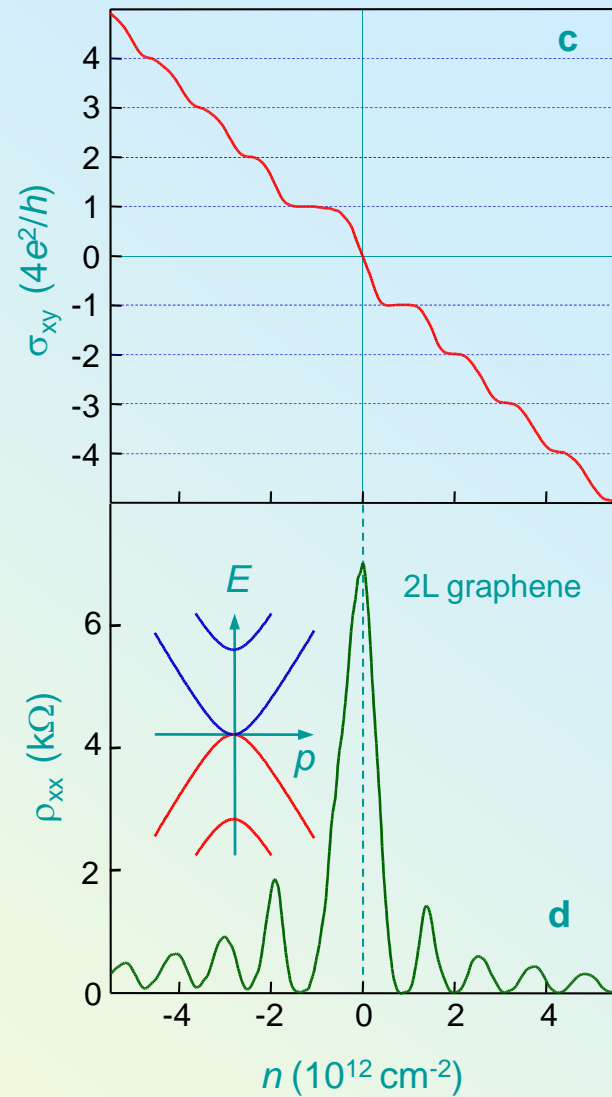
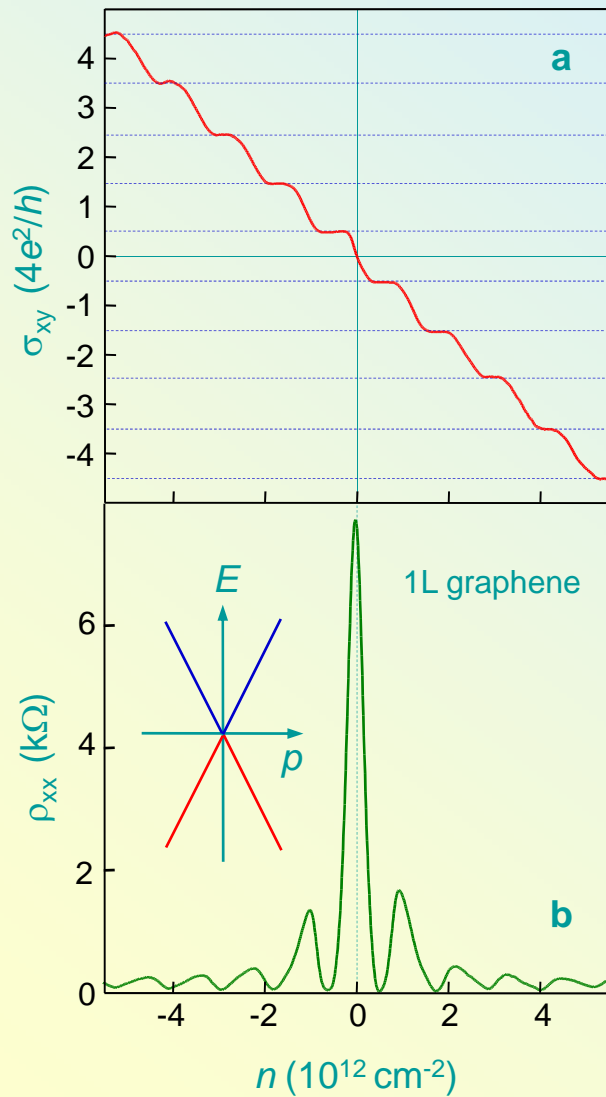


Bilayer

$$\varepsilon^\pm = \pm \hbar \omega_c \sqrt{n(n-1)}$$

with 8-fold degenerate $\varepsilon=0$ Landau level

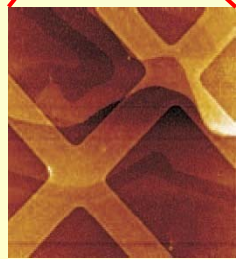
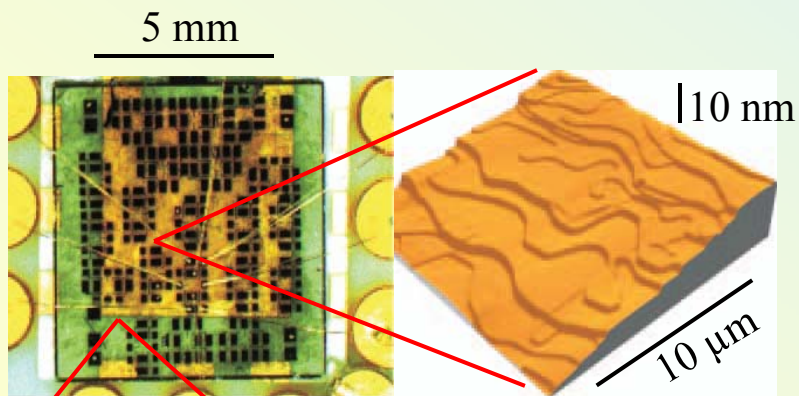
McCann & VF - PRL 96, 086805 (2006)



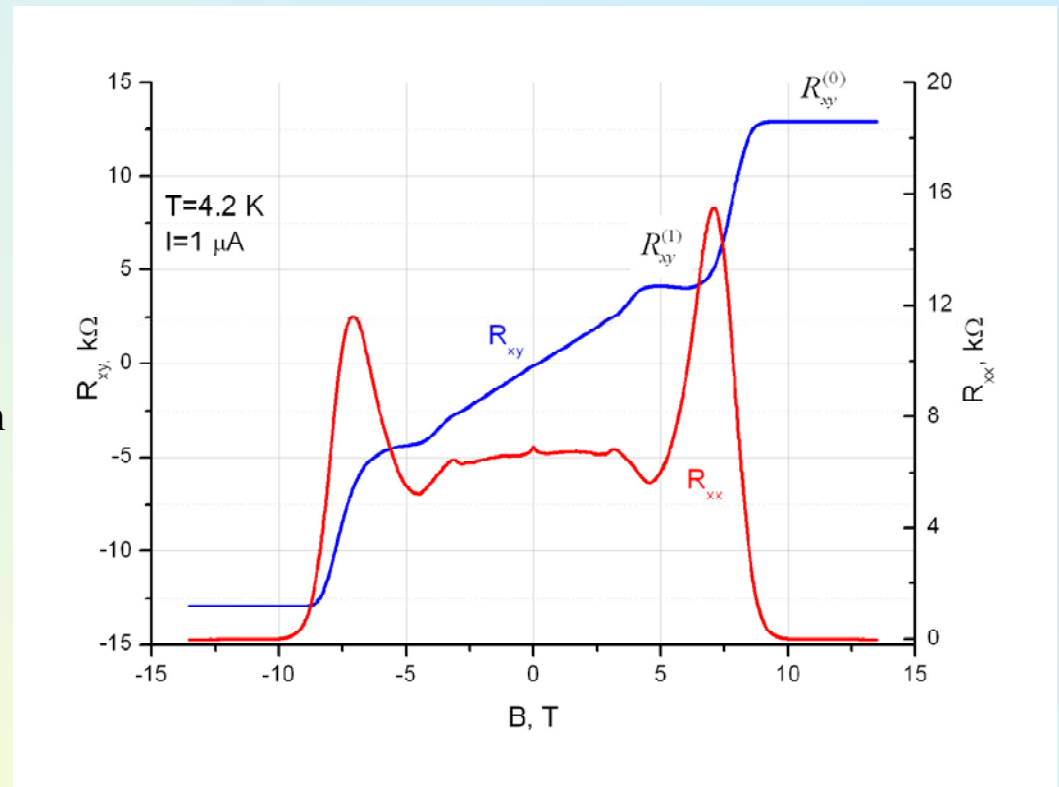
Unconventional quantum Hall effect and Berry's phase of 2π in bilayer graphene

Novoselov, McCann, Morozov, VF, Katsnelson, Zeitler, Jiang, Schedin, Geim
Nature Physics 2, 177 (2006)

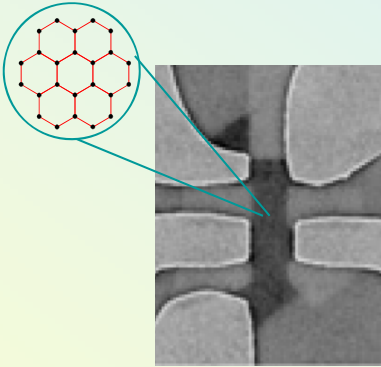
QHE resistance quantisation with accuracy of few parts per billion in graphene synthesised on SiC



10 μm



Tzalenchuk, Lara-Avila, Kalaboukhov, Paolillo, Syväjärvi, Yakimova, Kazakova, Janssen, VF, Kubatkin, Nature Nanotechnology 5, 186 - 189 (2010)



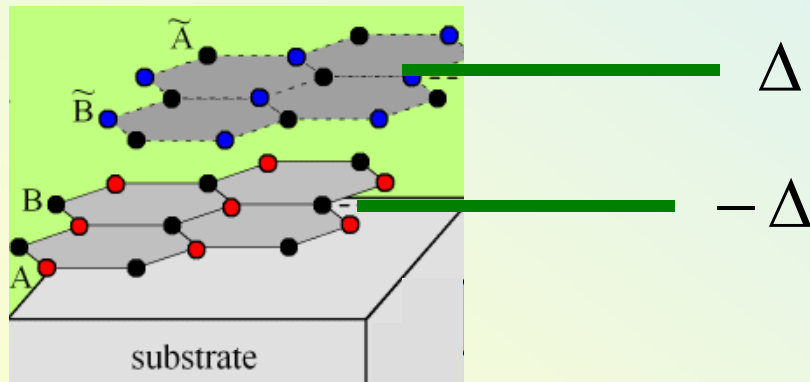
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Interlayer asymmetry gap in bilayer graphene

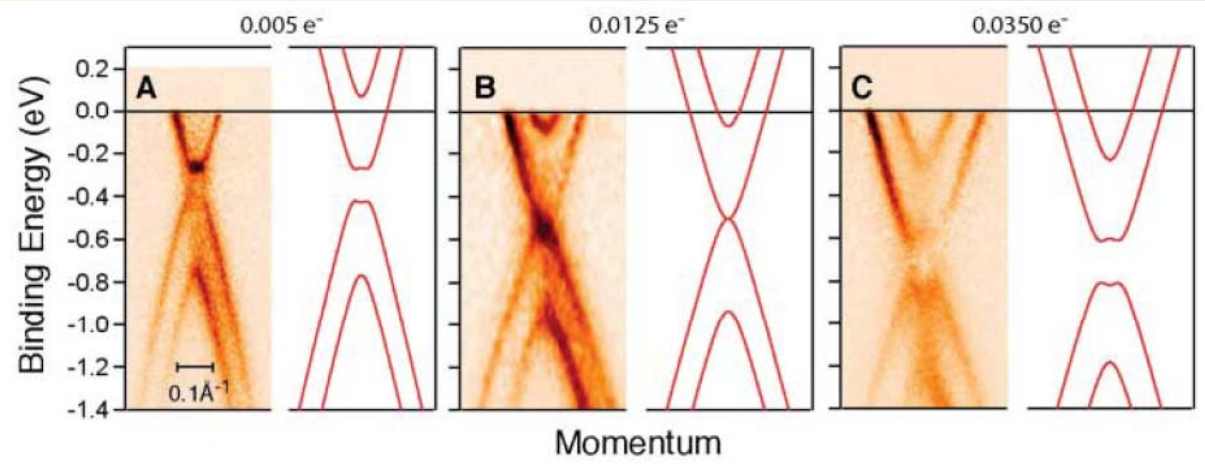
$$\hat{H}_2 = -\frac{v^2}{\gamma_1} \begin{pmatrix} 0 & (\pi^\dagger)^2 \\ \pi^2 & 0 \end{pmatrix} + \begin{pmatrix} \Delta & 0 \\ 0 & -\Delta \end{pmatrix}$$

**inter-layer
asymmetry gap
(can be controlled
using electrostatic
gates)**

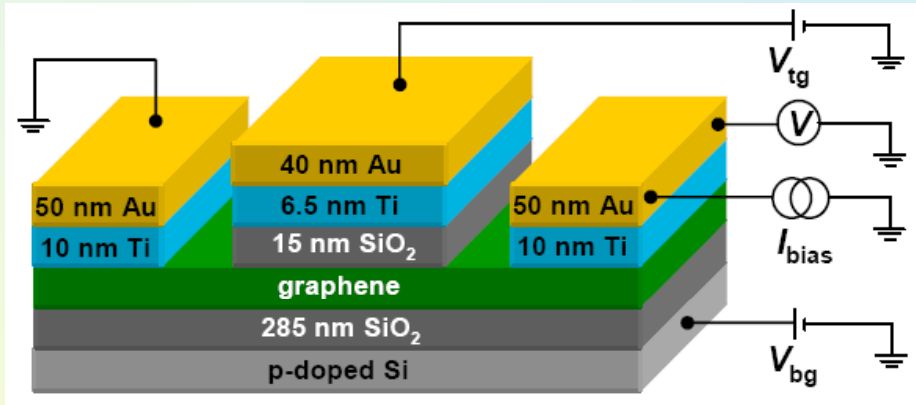


McCann & VF - PRL 96, 086805 (2006)
McCann - PRB 74, 161403 (2006)

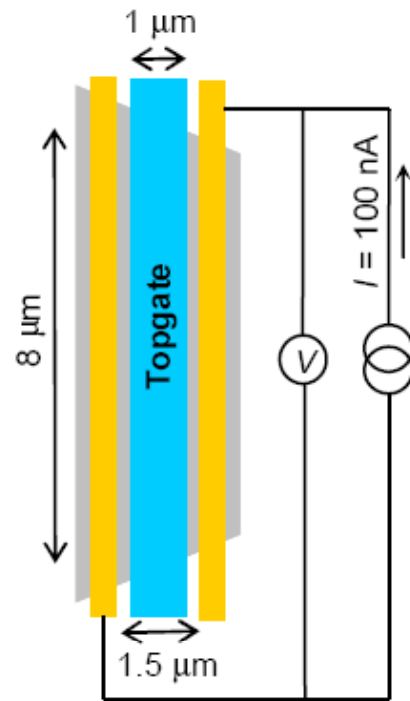
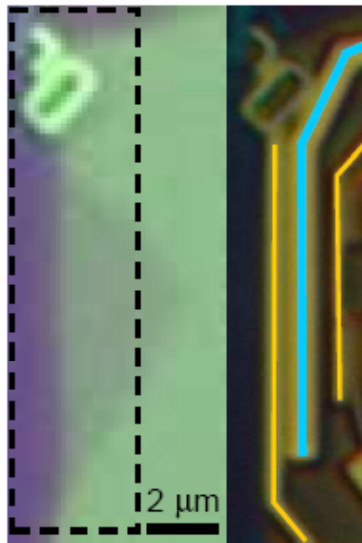
T. Ohta *et al* – Science 313, 951 (2006)
(Rotenberg's group at Berkeley NL)



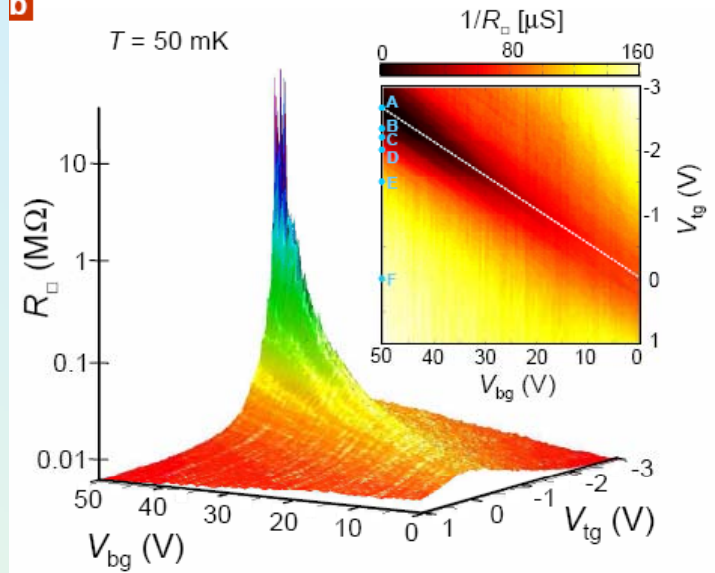
Gate-controlled interlayer asymmetry gap (transport measurements)



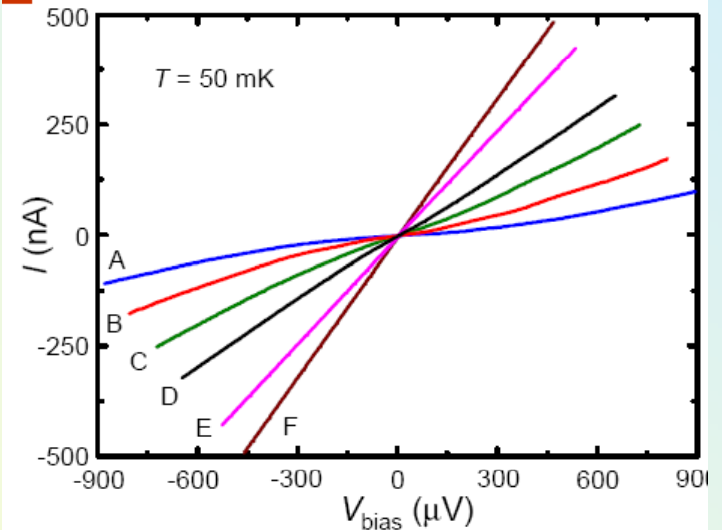
a



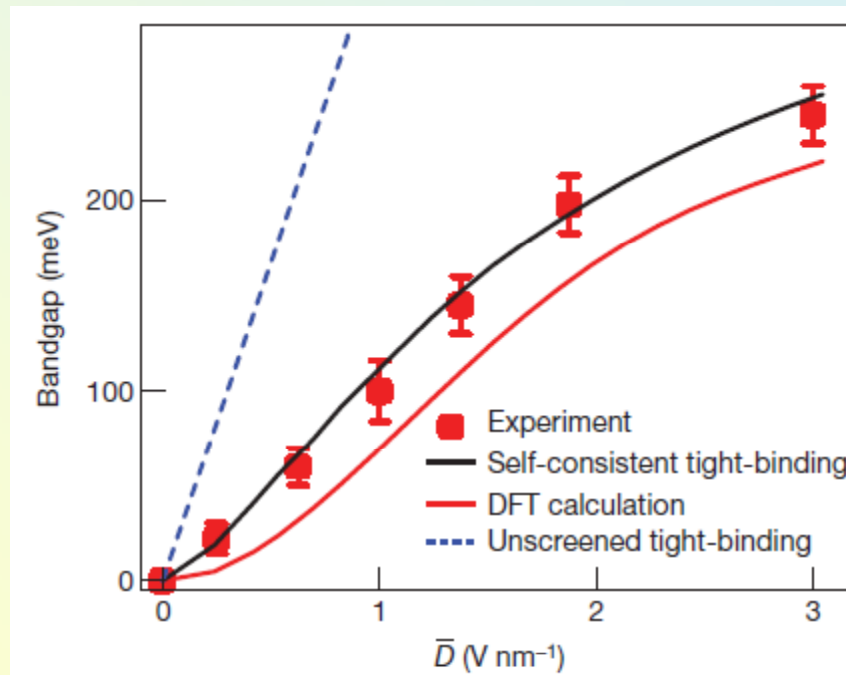
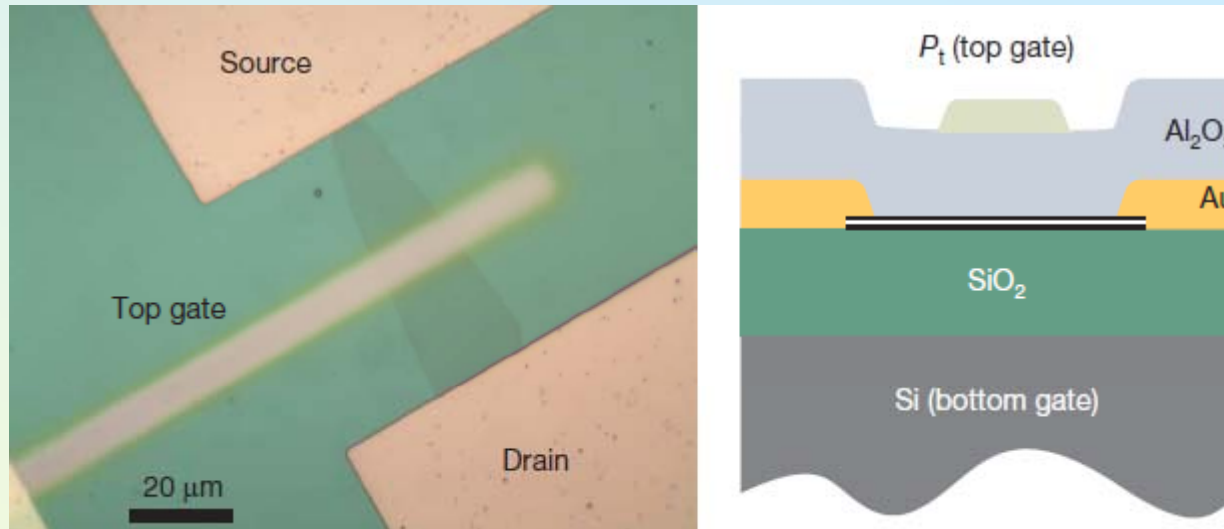
b



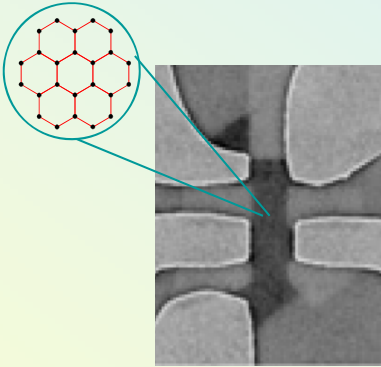
c



Oostinga, Heersche, Liu, Morpurgo, and Vandersypen - Nature Physics (2007)



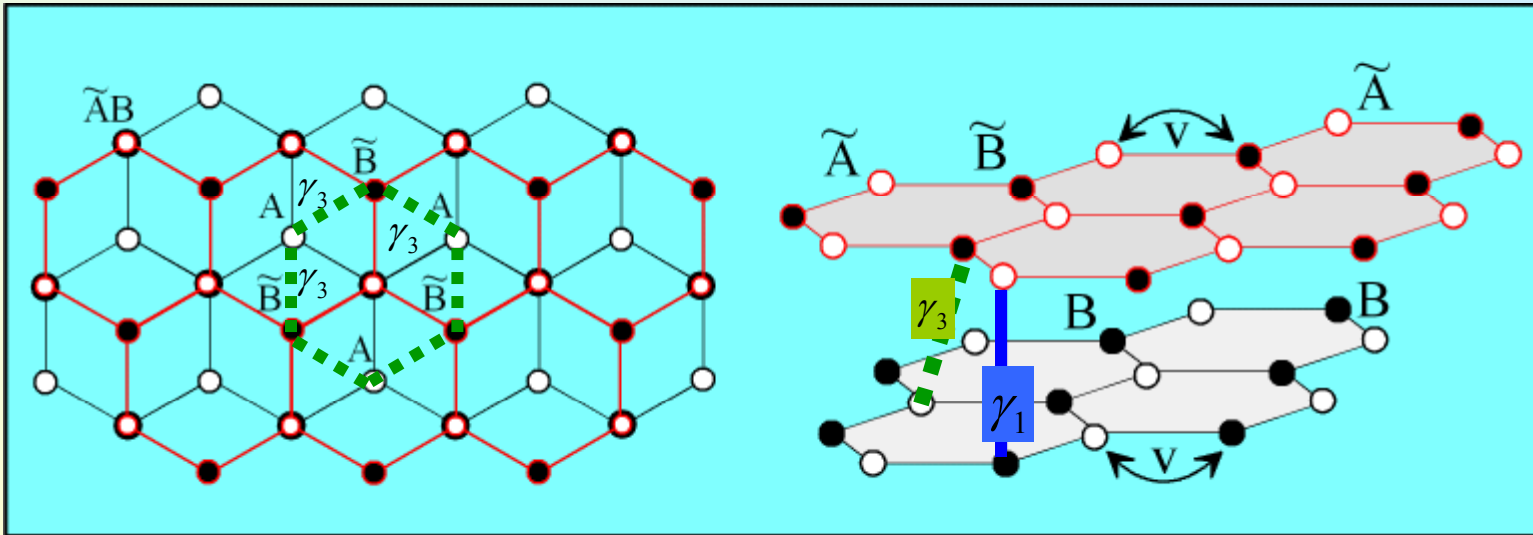
Zhang, Tang, Girit, Hao, Martin, Zettl, Crommie, Shen, Wang - Nature 459, 820 (2009)



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Direct interlayer hopping and the 'warping' term in BLG



$$v_3 = \frac{\sqrt{3}}{2} \frac{\gamma_3 a}{\hbar} \sim 0.1v$$

Direct inter-layer $A\tilde{B}$ hops
(the next neighbour coupling)

$$H = \begin{pmatrix} 0 & v_3\pi & 0 & v\pi^+ \\ v_3\pi^+ & 0 & v\pi & 0 \\ 0 & v\pi^+ & 0 & \gamma_1 \\ v\pi & 0 & \gamma_1 & 0 \end{pmatrix}$$

$$\hat{H}_2 = -\frac{v^2}{\gamma_1} \begin{pmatrix} 0 & (\pi^\dagger)^2 \\ \pi^2 & 0 \end{pmatrix} + v_3 \begin{pmatrix} 0 & \pi \\ \pi^\dagger & 0 \end{pmatrix}$$

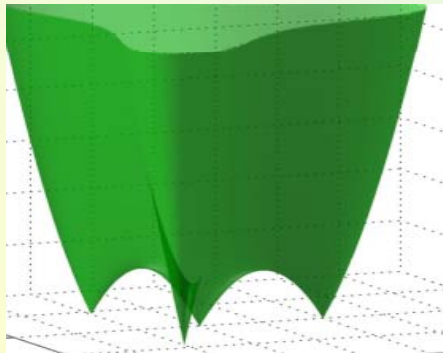
trigonal warping

$$\hat{H}_2 = -\frac{1}{2m} \begin{pmatrix} 0 & (\pi^\dagger)^2 \\ \pi^2 & 0 \end{pmatrix} + v_3 \begin{pmatrix} 0 & \pi \\ \pi^\dagger & 0 \end{pmatrix}$$

$$\pi = p e^{i\theta}$$

Berry phase

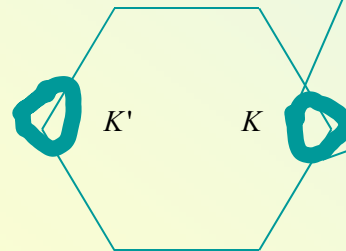
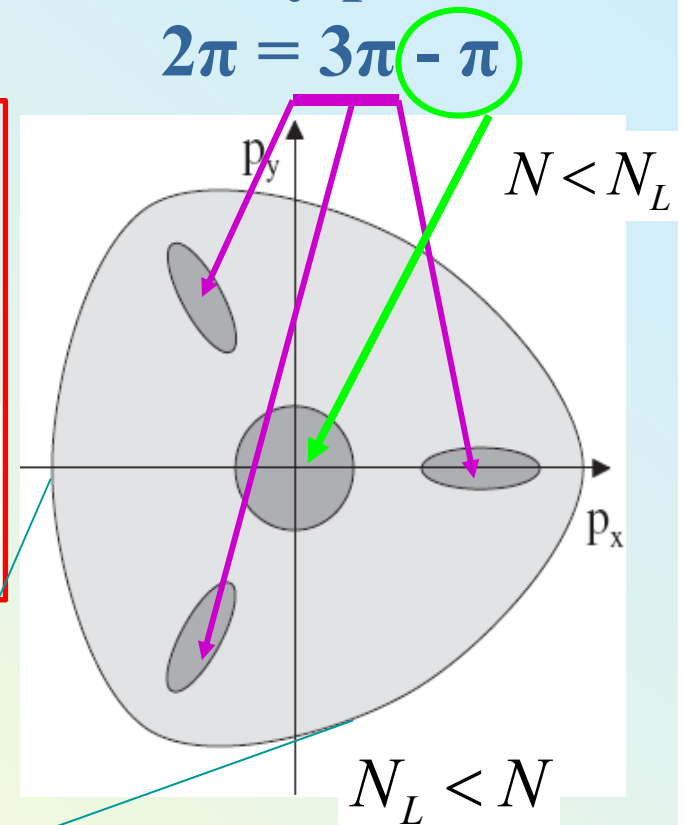
$$2\pi = 3\pi - \pi$$



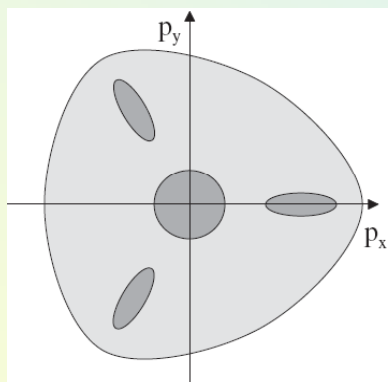
$$\varepsilon_{LiTr} = \frac{mv_3^2}{2} \sim 1meV$$

Lifshitz transition

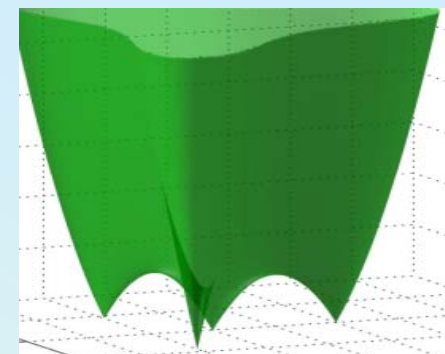
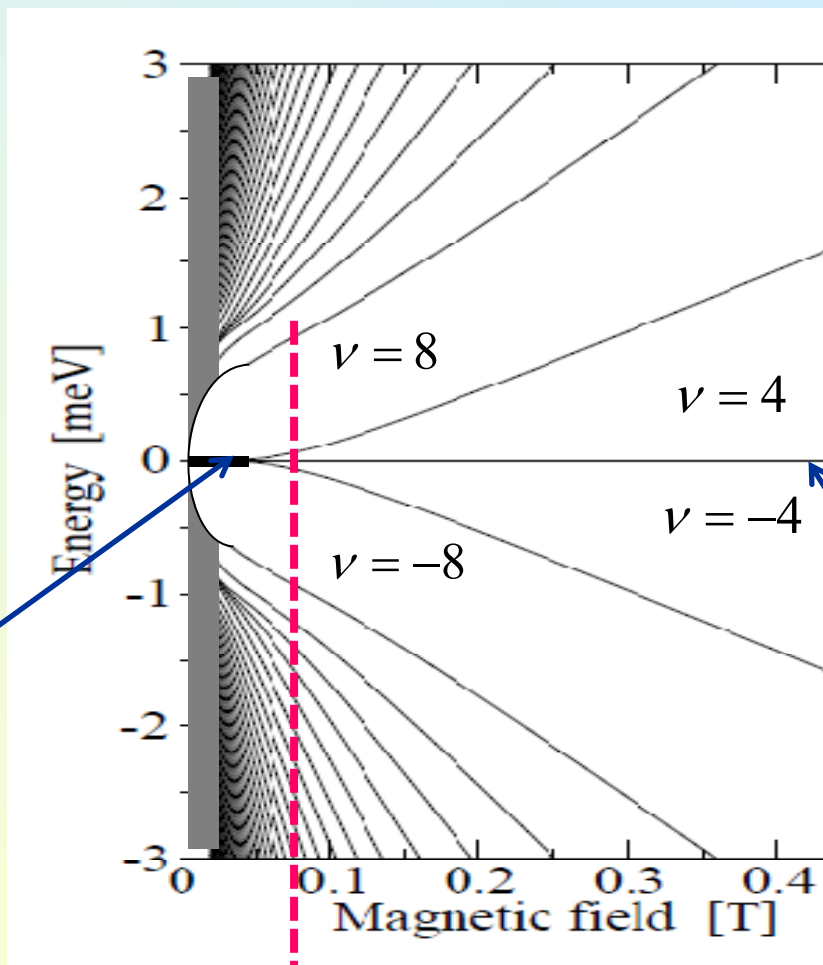
$$n_{LiTr} = \frac{2}{\pi^2} \left(\frac{mv_3}{\hbar} \right)^2 \sim 10^{10} cm^{-2}$$



Landau levels and magnetic breakdown



each Dirac point provides 4 LLs at $\epsilon=0$:
16-fold degenerate zero-energy LL



8-fold degenerate zero-energy Landau level (LL)

weak field

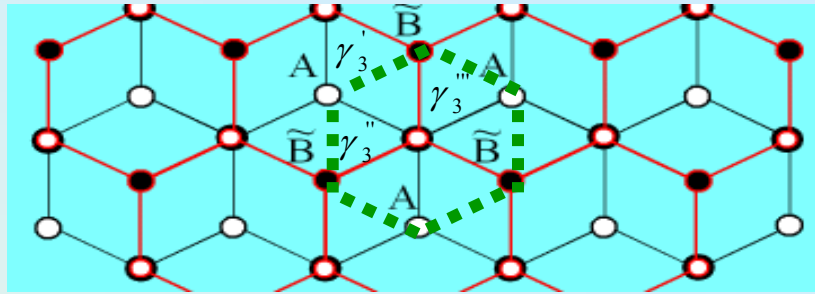
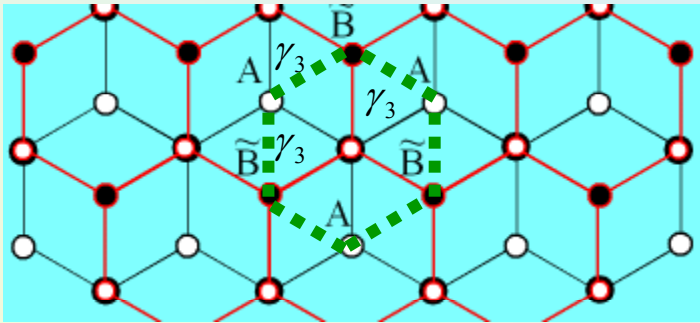
'magnetic breakdown' regime

strong field

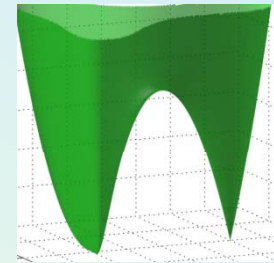
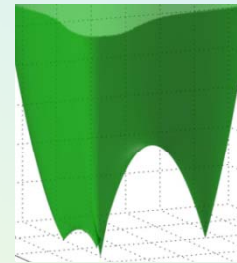
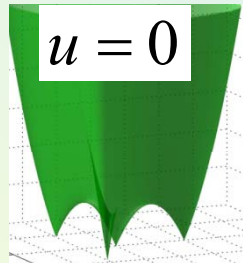
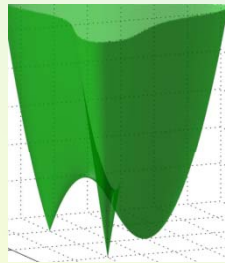
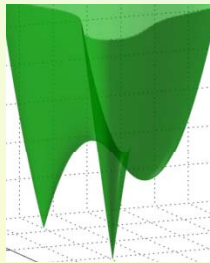
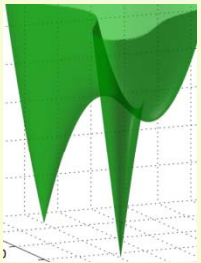
$$\lambda_B^{-1} \sim p \gg mv_3$$

$$\lambda_B^{-1} \sim mv_3$$

Slightly stretched bilayer graphene



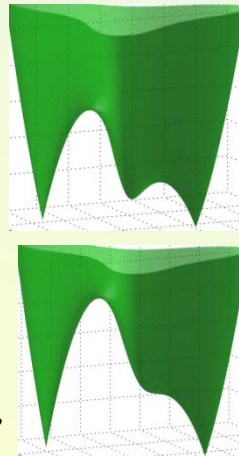
$$\hat{H} = -\frac{2}{2m} \begin{pmatrix} 0 & \pi^2 \\ (\pi^+)^2 & 0 \end{pmatrix} + \mathcal{S}v_3 \begin{pmatrix} 0 & \pi^+ \\ \pi & 0 \end{pmatrix} + \begin{pmatrix} 0 & u_1 + iu_2 \\ u_1 - iu_2 & 0 \end{pmatrix}$$



$u_1 < 0$

$2\pi = \pi + \pi$
Berry phase

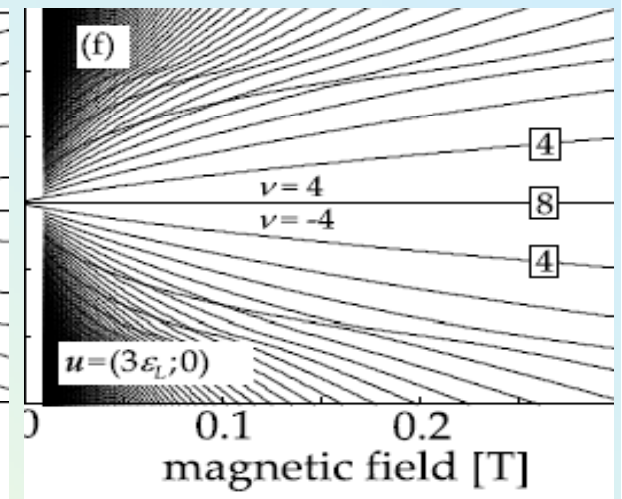
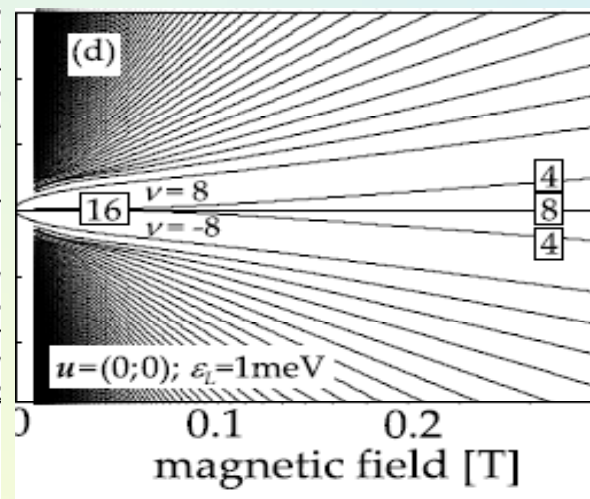
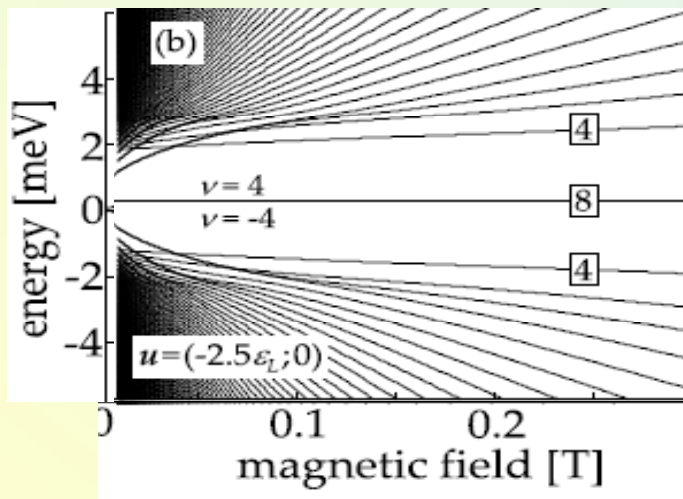
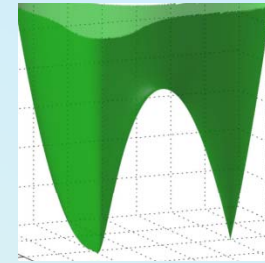
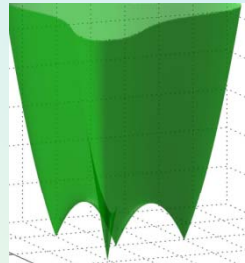
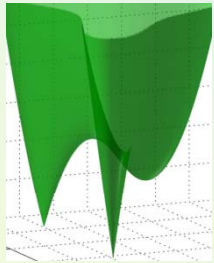
$|u_2|$



$u_1 > 0$

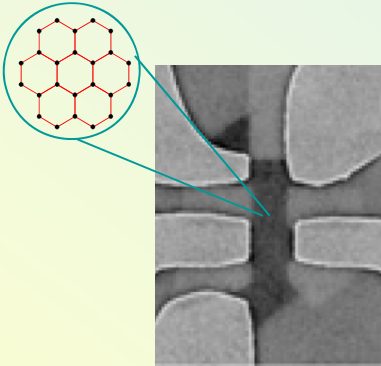
$2\pi = \pi + \pi + \pi - \pi$
 $= \pi + \pi$

Landau levels in slightly stretched bilayer graphene



Persistence of different filling factors in the QHE in low magnetic fields.

Electronic properties of graphene, from 'high' to 'low' energies.



Graphene for beginners: tight-binding model.
Berry phase π electrons in monolayers.
Trigonal warping. Stretched graphene.
PN junction in graphene.

Berry phase 2π electrons in bilayer graphene.
Landau levels & QHE. Interlayer asymmetry gap.
Lifshitz transition and magnetic breakdown in BLG. Stretched BLG.
Symmetry and irreducible representations for honeycomb crystals.
Renormalisation group theory for interaction and spontaneous
symmetry breaking in BLG.

Is the symmetric state of the electronic liquid in bilayer graphene stable against spontaneous symmetry breaking of U_4 symmetry due to e-e interaction?

$$U_4 : \quad \psi = \begin{pmatrix} A + \\ \tilde{B} + \\ \tilde{B} - \\ A - \end{pmatrix} \rightarrow \psi' = [\text{unitary } 4 \times 4 \text{ matrix}] \psi$$

Here - BLG in a zero magnetic field, where one may think of many possible phase transitions:
ferromagnetic
ferroelectric (excitonic insulator)
density wave state
superconducting (s or p)

For a BLG at a high magnetic field, the e-e interaction lifts the infinite degeneracy of the LL states:
spin-polarised $\nu=1$ and 3 (QHFM)
valley polarized $\nu=2$ (QHFE)
fractional QHE states.
(lectures by Eva Andrei)

How shall we approach the problem:

Classify possible phases using irreducible representations of the symmetry group of the crystal.

Identify relevant e-e interaction channels potentially responsible for the spontaneous symmetry breaking.

Using renormalisation group approach, determine which interaction channel has the fastest growing constant in the RG flow, which determines the most plausible phase transition to occur in a BLG with low Fermi energy of electrons.

basis of 4x4 matrices

$$\psi = \begin{pmatrix} A, K \\ B, K \\ B, K' \\ A, K' \end{pmatrix}$$

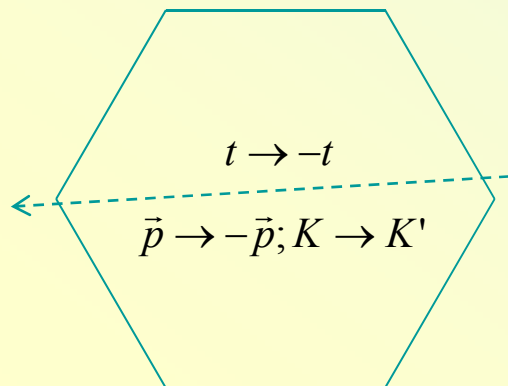
sublattice matrices

$$\Sigma_1 = \begin{bmatrix} \sigma_x & 0 \\ 0 & -\sigma_x \end{bmatrix} \quad \Sigma_2 = \begin{bmatrix} \sigma_y & 0 \\ 0 & -\sigma_y \end{bmatrix} \quad \Sigma_3 = \begin{bmatrix} \sigma_z & 0 \\ 0 & \sigma_z \end{bmatrix} \quad [\Sigma_{s_1}, \Sigma_{s_2}] = 2i\epsilon^{s_1 s_2 s_3} \Sigma_{s_3}$$

valley matrices

$$\Lambda_1 = \begin{bmatrix} 0 & \sigma_z \\ \sigma_z & 0 \end{bmatrix} \quad \Lambda_2 = \begin{bmatrix} 0 & -i\sigma_z \\ i\sigma_z & 0 \end{bmatrix} \quad \Lambda_3 = \begin{bmatrix} \sigma_0 & 0 \\ 0 & -\sigma_0 \end{bmatrix} \quad [\Lambda_{l_1}, \Lambda_{l_2}] = 2i\epsilon^{l_1 l_2 l_3} \Lambda_{l_3}$$

$$[\Sigma_s, \Lambda_l] = 0$$

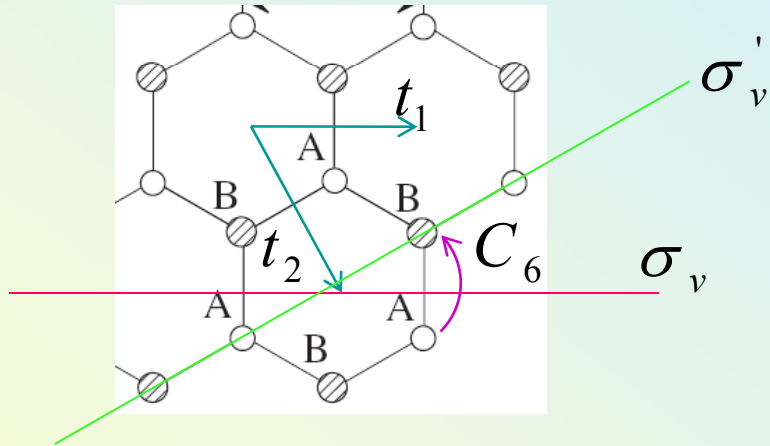


$\vec{\Sigma}, \vec{\Lambda}$ invert signs

$I, \vec{\Sigma} \otimes \vec{\Lambda}$ invariant

16 generators of the group U_4

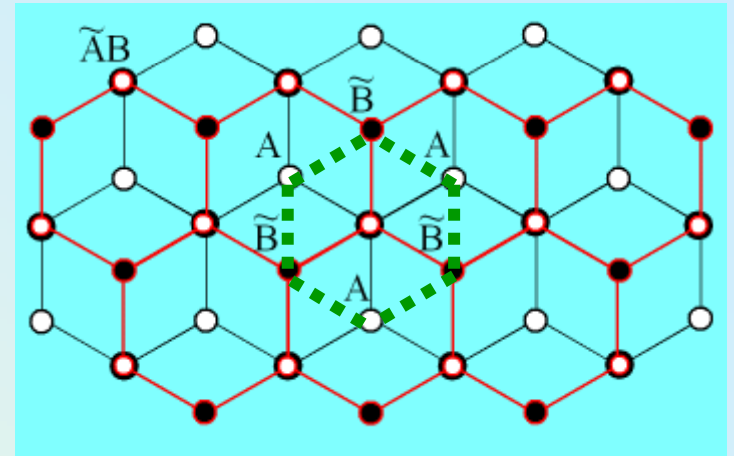
Monolayer C_{6v}



$$C_3 \rightarrow C_6^2$$

$$C_2 \rightarrow C_6^3$$

bilayer $C_{6v(z)}$



$\mathbb{1}$	t_1 t_2	C_2 $t_1 C_2$ $t_2 C_2$	C_3 C_3^2	$C_3 t_1$ $C_3^2 t_1$ $C_3 t_2$ $C_3^2 t_2$	C_6 C_6^5 $C_6 t_1$ $C_6^5 t_1$ $C_6 t_2$ $C_6^5 t_2$	$3\sigma_v$ $3t_1\sigma_v$ $3t_2\sigma_v$	$3\sigma'_v$	$3t_1\sigma'_v$ $3t_2\sigma'_v$
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$$\sigma_v \rightarrow \sigma_v \sigma_z$$

$$C_6 \rightarrow C_6 \sigma_z$$



Irreducible representations of the symmetry group of a honeycomb crystal

	$\mathbb{1}$	t_1 t_2	C_2 $t_1 C_2$ $t_2 C_2$	C_3 C_3^2	$C_3 t_1$ $C_3^2 t_1$ $C_3 t_2$ $C_3^2 t_2$	C_6 C_6^5 $C_6 t_1$ $C_6^5 t_1$ $C_6 t_2$ $C_6^5 t_2$	$3\sigma_v$ $3t_1 \sigma_v$ $3t_2 \sigma_v$	$3\sigma'_v$	$3t_1 \sigma'_v$ $3t_2 \sigma'_v$	
A_1	1	1	1	1	1	1	1	1	1	\hat{M}_0^0
B_1	1	1	-1	1	1	-1	1	-1	-1	\hat{M}_3^3
A_2	1	1	1	1	1	1	-1	-1	-1	\hat{M}_0^3
B_2	1	1	-1	1	1	-1	-1	1	1	\hat{M}_3^0
E_1	2	2	-2	-1	-1	1	0	0	0	$\begin{pmatrix} \hat{M}_0^1 \\ \hat{M}_0^2 \end{pmatrix}$
E_2	2	2	2	-1	-1	-1	0	0	0	$\begin{pmatrix} \hat{M}_3^1 \\ \hat{M}_3^2 \end{pmatrix}$
E'	2	-1	0	2	-1	0	0	2	-1	$\begin{pmatrix} \hat{M}_1^0 \\ \hat{M}_2^0 \end{pmatrix}$
E''	2	-1	0	2	-1	0	0	-2	1	$\begin{pmatrix} \hat{M}_1^3 \\ \hat{M}_2^3 \end{pmatrix}$
G	4	-2	0	-2	1	0	0	0	0	$\begin{pmatrix} \hat{M}_1^1; \hat{M}_2^1 \\ \hat{M}_1^2; \hat{M}_2^2 \end{pmatrix}$

$$M_l^s = \Lambda_l \Sigma_s$$

phenomenology

$$\Sigma_0 = \Lambda_0 = I \quad H = \sum \text{inv}(M_l^s, \vec{p})$$

interlayer asymmetry ΔM_3^3

strain $u_1 M_3^1 + u_2 M_3^2$

$$\psi = \begin{pmatrix} A \ K \\ \tilde{B} \ K \\ \tilde{B} \ K' \\ A \ K' \end{pmatrix} \rightarrow$$

symmetry-breaking by an order parameter

$$X_l^s \propto \langle \psi^\dagger M_l^s \psi \rangle$$

$$M_l^s \in \text{Irrep}$$

$$H_2 = -\frac{1}{2m} \left[(p_x^2 - p_y^2) M_3^1 - 2p_x p_y M_3^1 \right] + v_3 \left[p_x M_0^1 + p_y M_0^2 \right]$$

e-e interaction in various channels

$$H_C = \frac{e^2}{2} \int d^2r d^2r' \frac{\psi_r^+ \psi_r \psi_{r'}^+ \psi_{r'}}{|\mathbf{r} - \mathbf{r}'|}$$

$$H_{sr} = \frac{2\pi}{m} \sum_{l,s} g_l^s \int d^2r \left[\psi_r^+ M_l^s \psi_r \right]^2$$

$$M_l^s = \Lambda_l \Sigma_s$$

$$\Sigma_0 = \Lambda_0 = I$$

Irreps. of
symmetry group
of honeycomb lattice

strain $g_3^1 = g_3^2 = g_{E_2}$

interlayer asymmetry
(ferroelectric fluctuations) $g_3^3 = g_{B_1}$

$g_0^3 = g_{A_2}$

$g_3^0 = g_{B_2}$

charge-density
wave $g_1^3 = g_2^3 = g_{E''}$

$g_1^0 = g_2^0 = g_{E'}$

$g_0^1 = g_0^2 = g_{E_1}$

$g_1^1 = g_2^2 = g_1^2 = g_2^1 = g_G$

How shall we approach the problem:

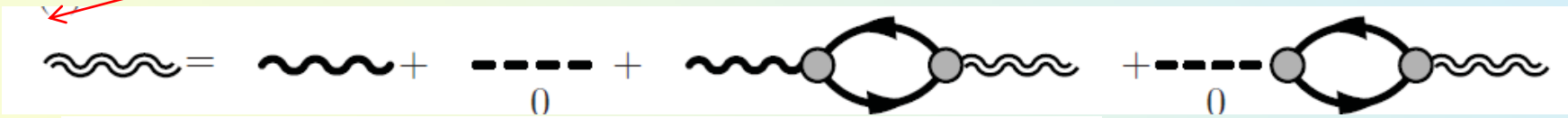
We have classified possible phases and relevant e-e interaction channels using irreducible representations of the symmetry group of the crystal...

... but the only thing that we know is that Coulomb interaction is strong, whereas interaction in all other channels is weak and difficult to estimate microscopically.

Using renormalisation group approach, we determine which interaction channel has the fastest growing constant in the RG flow, which determines the most plausible phase transition to occur for BLG with a small Fermi energy of electrons.

Screening of Coulomb interaction

$$\omega, \vec{q} = -\frac{2\pi e^2}{|\vec{q}|}; \quad \begin{array}{c} \bullet \rightarrow \\ \vdots \\ \bullet \leftarrow \end{array} = -\frac{4\pi}{m} g_0^0 \hat{M}_0^0 \otimes \hat{M}_0^0; \quad \begin{array}{c} \bullet \rightarrow \\ \vdots \\ \bullet \leftarrow \end{array} = -\frac{4\pi}{m} \sum_{i,j=0}^3 g_i^j \hat{M}_i^j \otimes \hat{M}_i^j$$



$$= - \left[\left(\frac{2\pi e^2}{|q|} + \frac{4\pi}{m} g_0^0 \right)^{-1} + \Pi \right]^{-1} = -\frac{\pi D \left(\frac{2m\omega}{q^2} \right)}{mN}$$

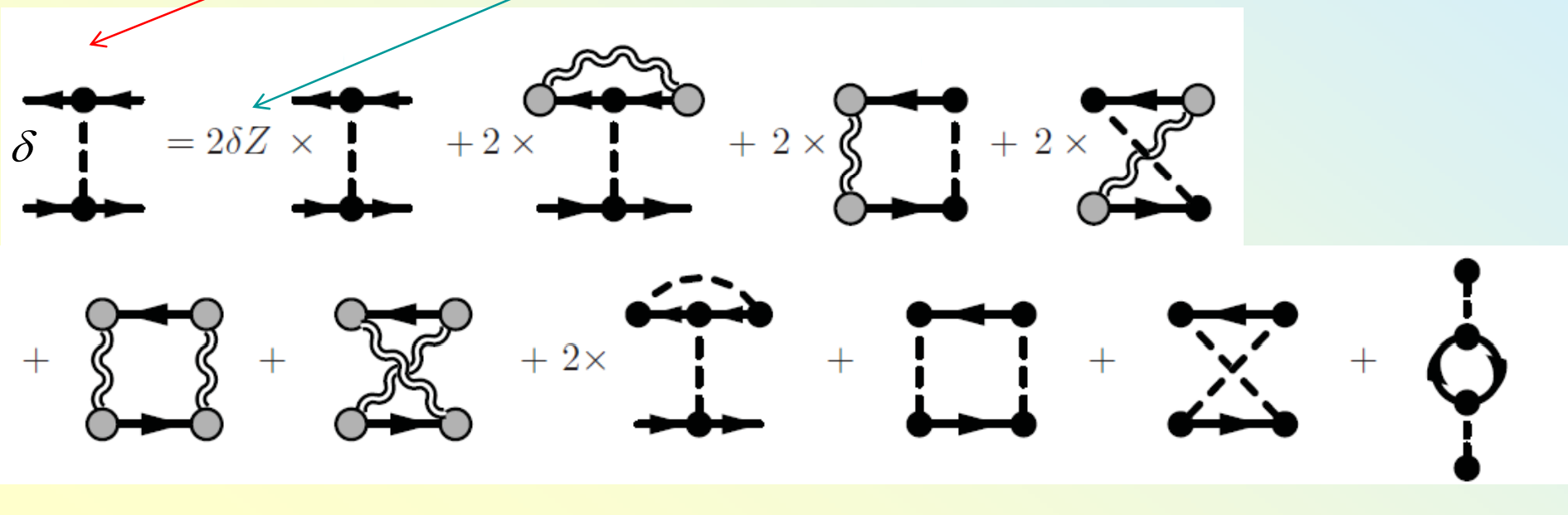
'large' $N=4$ (valley*spin) $\implies 1/N$ expansion

$$\omega, q = \Pi(q, \omega) = \frac{Nm}{\pi D \left(\frac{2m\omega}{q^2} \right)}; \quad D(x) = \left[\ln \left(\frac{4x^2 + 4}{4x^2 + 1} \right) + \frac{2 \arctan x - \arctan(2x)}{x} \right]^{-1}$$

Renormalisation of short-range interactions

$$\begin{aligned}
 \text{wavy line } \omega, \vec{q} &= -\frac{2\pi e^2}{|\vec{q}|}; & \text{tadpole } 0 &= -\frac{4\pi}{m} g_0^0 \hat{M}_0^0 \otimes \hat{M}_0^0; & \text{tadpole } &= -\frac{4\pi}{m} \sum_{i,j=0}^3 g_i^j \hat{M}_i^j \otimes \hat{M}_i^j
 \end{aligned}$$

$$\delta Z = \frac{i\partial}{\partial\epsilon} \text{ (tadpole diagram with wavy line) } k=0$$

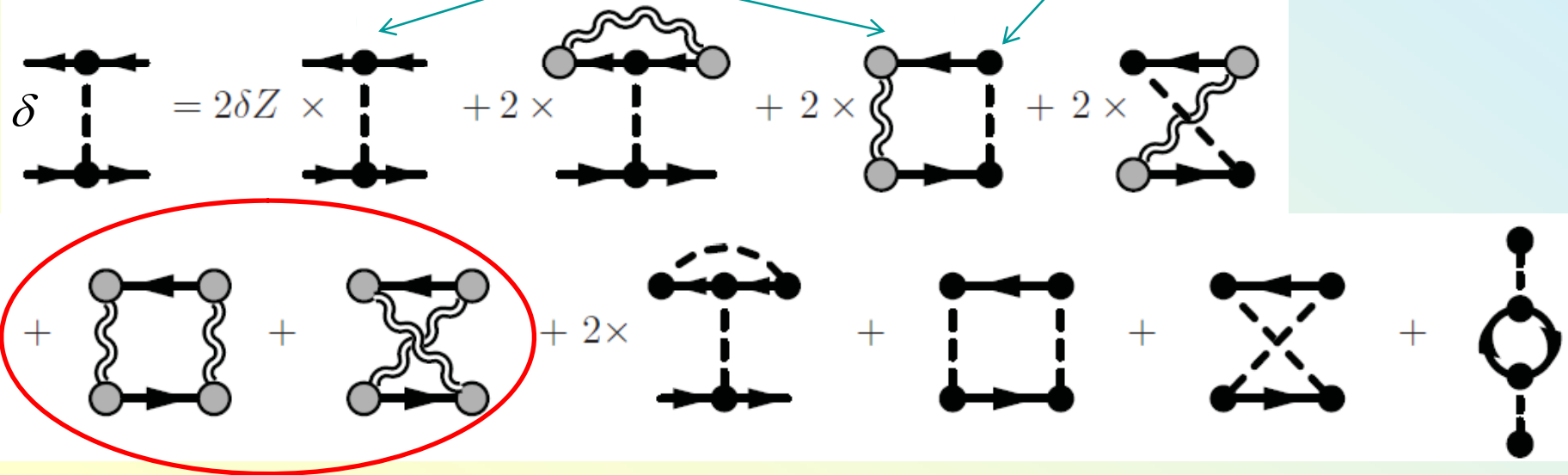


Renormalisation of short-range interactions

$$\begin{aligned}
 \text{wavy line } \omega, \vec{q} &= -\frac{2\pi e^2}{|\vec{q}|}; & \text{dashed line } 0 &= -\frac{4\pi}{m} g_0^0 \hat{M}_0^0 \otimes \hat{M}_0^0; & \text{dashed line } &= -\frac{4\pi}{m} \sum_{i,j=0}^3 g_i^j \hat{M}_i^j \otimes \hat{M}_i^j
 \end{aligned}$$

Some diagrams are infrared divergent, Nandkishore & Levitov; arXiv:0907.5395v1

but for combination of diagrams this \ln^2 divergence cancels leaving only \ln
 arXiv:0907.5395v2 [PRL 104, 156803, (2010)]



Vafeek & Yang, PRB 81, 041401 (2010)

RG treatment of short range interactions with 3 couplings

$$\ell = \ln \frac{\frac{1}{2} \gamma_1}{D} \equiv 2 \ln \frac{L}{\lambda(\frac{1}{2} \gamma_1)}$$

$$\frac{d \ln m}{d \ell} = - \frac{d \ln v_3}{d \ell} = \frac{0.08}{N}$$

$$\delta(E_2)_{i=3}^{j=1,2} = 1 \text{ and } \delta(E_2)_i^j = 0 \text{ otherwise}$$

$$\frac{dg_i^j}{d\ell} = - \frac{\tilde{\alpha} \delta(E_2)_i^j}{N^2} - \frac{\alpha_1 g_i^j}{N} - N B_i^j (g_i^j)^2 - \sum_{k,l,m,n=0}^3 C_{i;km}^{j;ln} \tilde{g}_k^l \tilde{g}_m^n$$

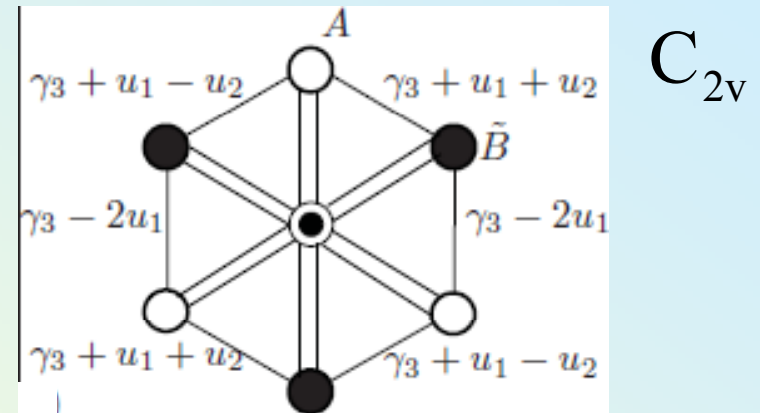
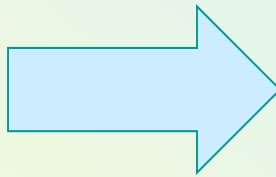
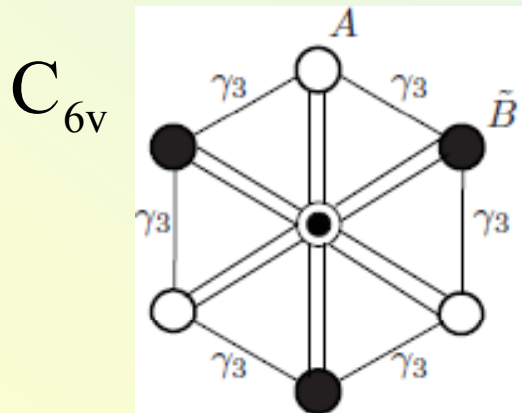
$$\frac{dg_{E_2}}{d\ell} = - \frac{c_1}{N(N+2)} - 2(N+2)(g_{E_2} - c_2)^2$$

$$g_{E_2}(\ell) = c_2 - \sqrt{\frac{c_1}{2N(N+2)^2}} \cot \left[\sqrt{\frac{2c_1}{N}} (\ell_0 - \ell) \right]$$

Symmetry-breaking happens first in the channel which corresponds to the uniaxial interlayer bond deformation (mimicking \tilde{A} -B sublattice shift in strained BLG).

Faster divergence of the interaction constant
in the 'uniaxial deformation' interaction channel (Irrep E_2)
(similar to the effect of strain)
signals possible instability - a phase transition.

Lemonik, Aleiner, Toke, VF, arXiv:1006.1399

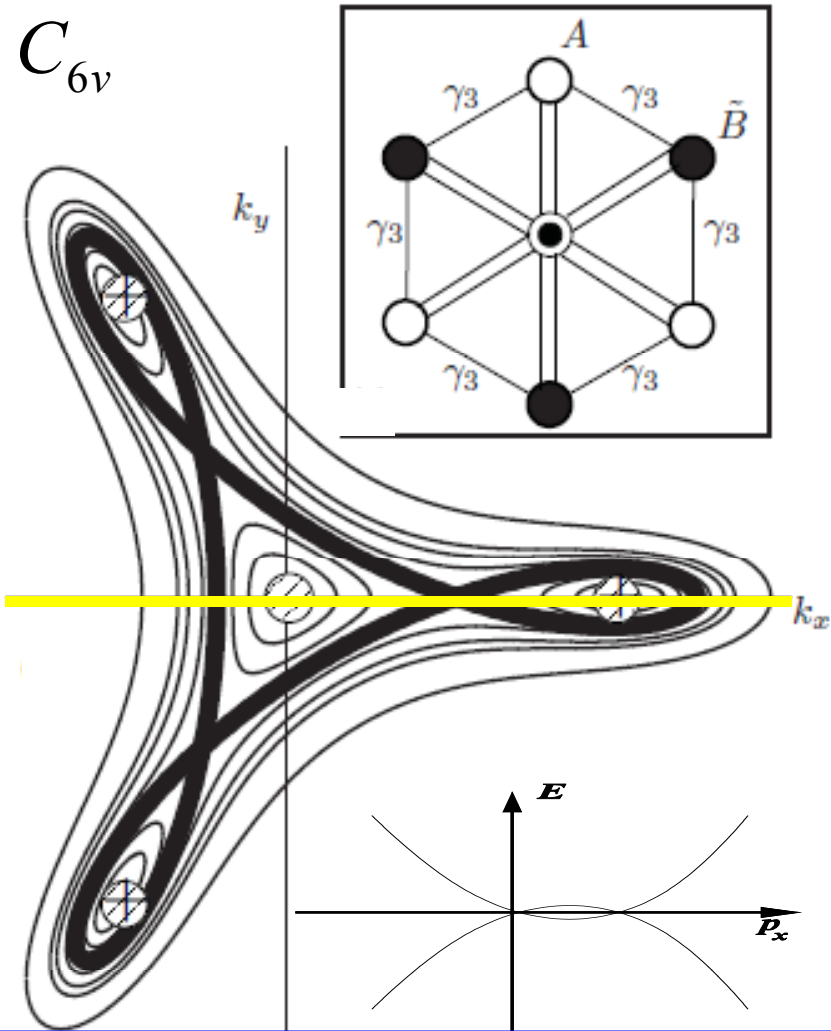


$$u_{1,2} = \frac{2\pi g_{E_2}}{m} \langle \psi^\dagger M_3^{1,2} \psi \rangle$$

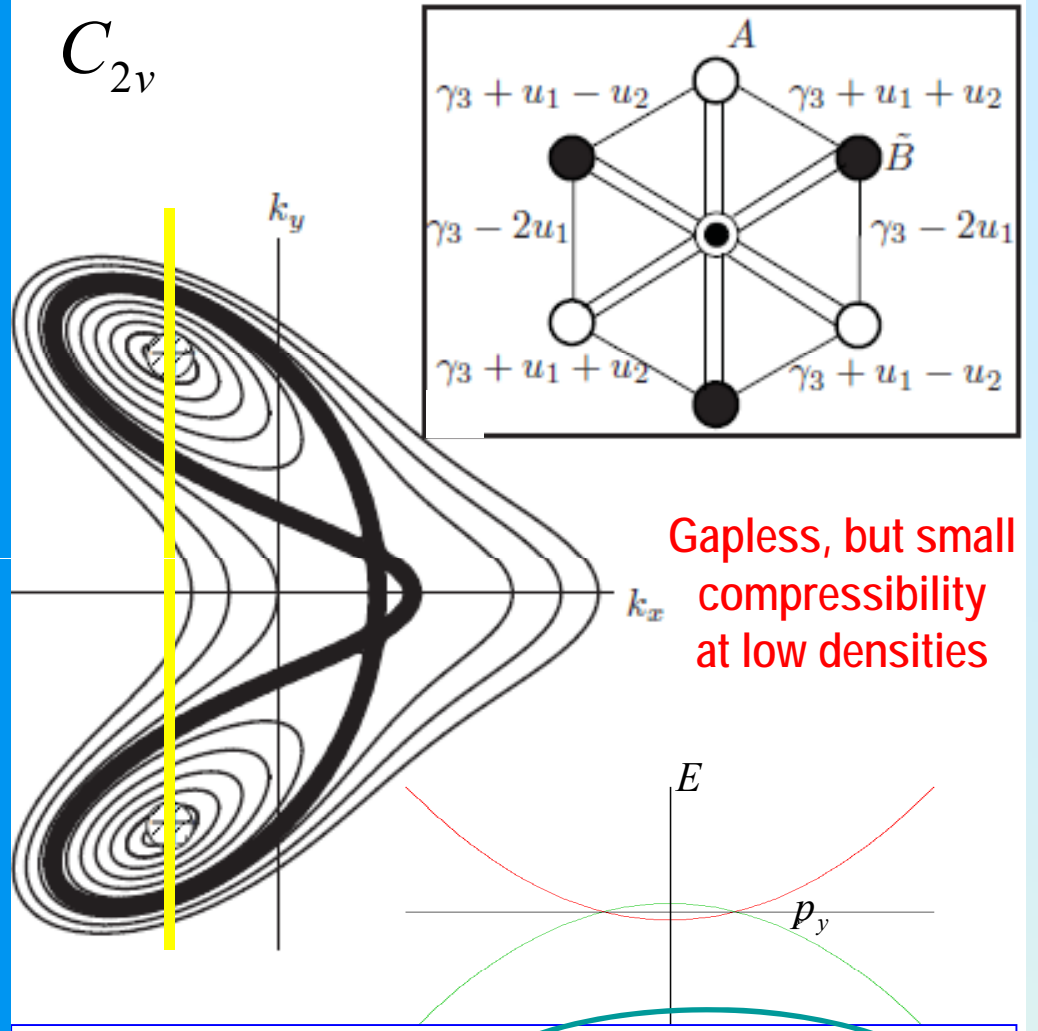
order parameter:
director $u=(u_1, u_2)$

Due to the lattice symmetry this
transition (at $\varepsilon_F \sim 0.2 \div 0.5 \text{ meV}$,
 $n_e \sim 10^9 \text{ cm}^{-2}$)
must be of the 1st order at $T=0$

$$f = n_{LiTr} \mathcal{E}_{LiTr} \mathcal{F}_\Upsilon \left(\frac{u_1^2 + u_2^2}{\mathcal{E}_{LiTr}^2}; \frac{u_1^3 - 3u_1 u_2^2}{\mathcal{E}_{LiTr}^3} \right)$$

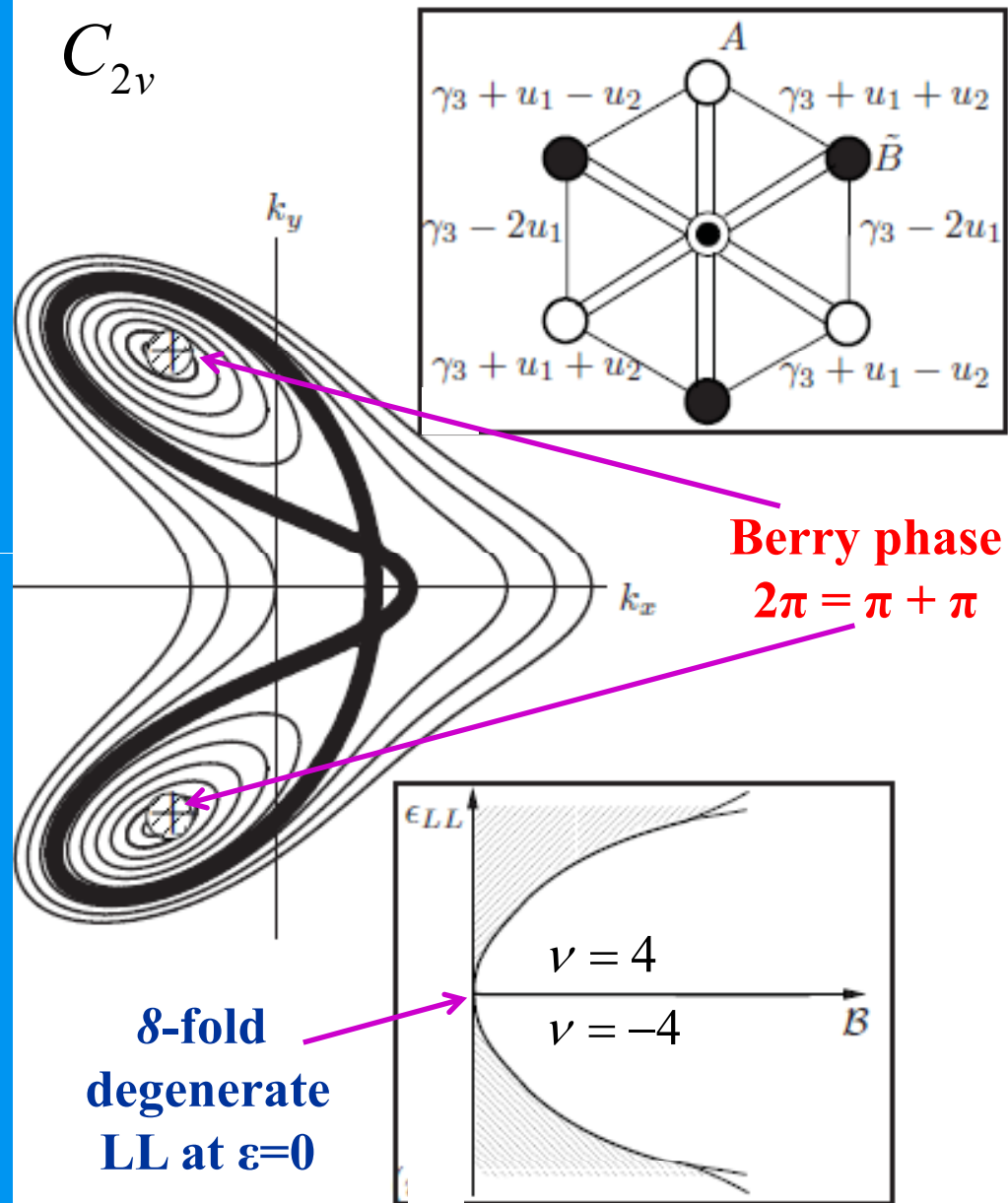
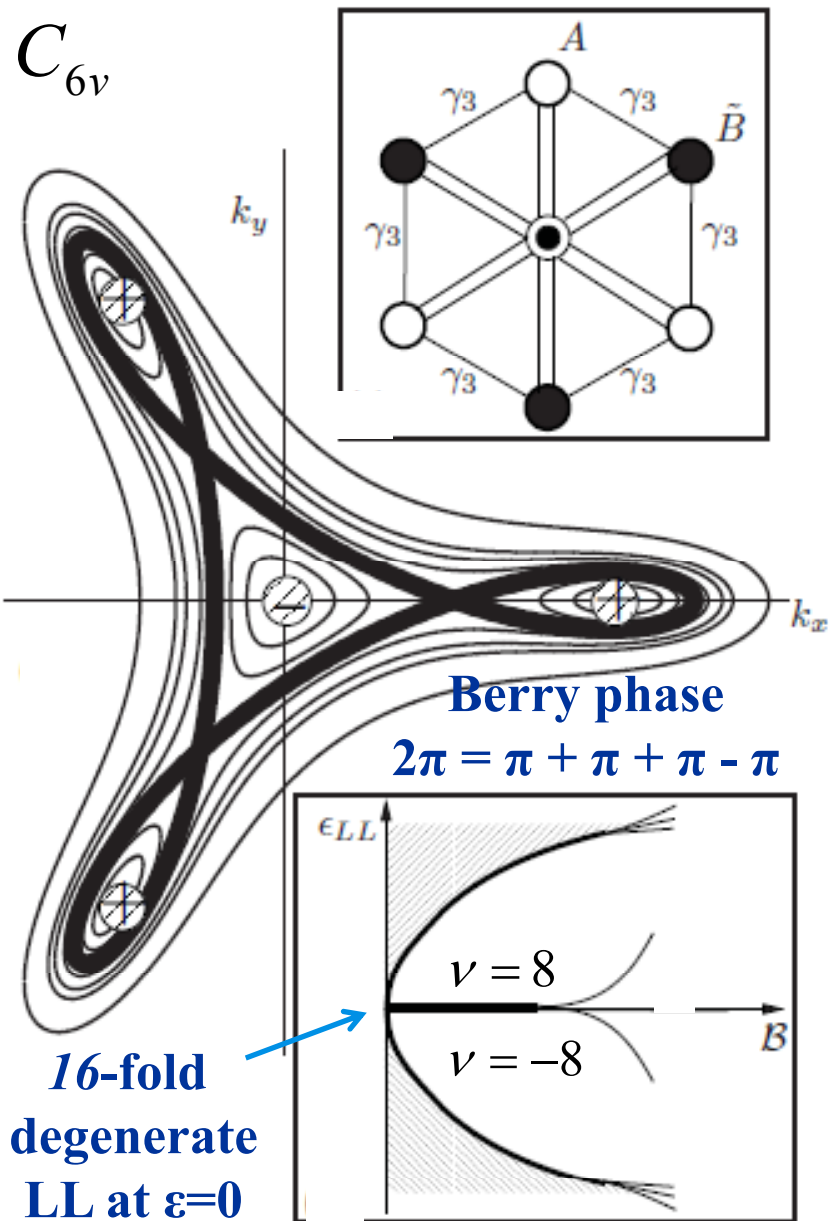
C_{6v} 

$$H_{C_{6v}} = \begin{pmatrix} 0 & -\frac{\pi^+{}^2}{2m} + v_3\pi \\ -\frac{\pi^2}{2m} + v_3\pi^+ & 0 \end{pmatrix}$$

 C_{2v} 

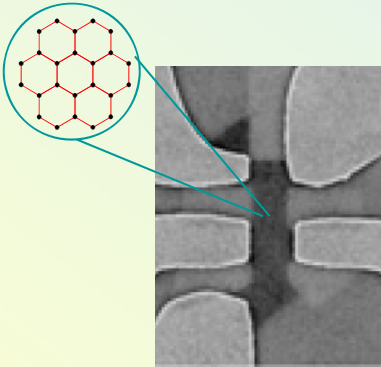
Gapless, but small compressibility at low densities

$$H_{C_{2v}} = \begin{pmatrix} 0 & -\frac{\pi^+{}^2}{2m} + v_3\pi + u_1 + iu_2 \\ []^+ & 0 \end{pmatrix}$$



Two phases can be distinguished by the persistence of different filling factors
 In the Shoubnikov – de Haas oscillations (or QHE) into low magnetic fields

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